

BZX84C2V0 - BZX84C75

350mW SURFACE MOUNT ZENER DIODES

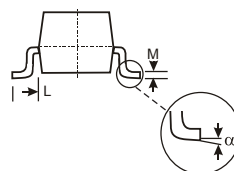
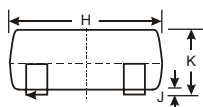
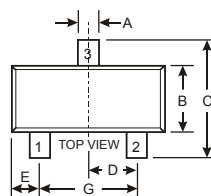
Features

- Planar Die Construction
- 350mW Power Dissipation
- Zener Voltages from 2.4V - 75V
- Ideally Suited for Automated Assembly Processes

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

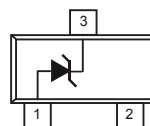
Parameter	Symbol	Value	Unit
Power Dissipation	P_D	350	mW
Thermal Resistance, Junction to Ambient ¹⁾	$R_{\theta JA}$	357	$^\circ\text{C}/\text{W}$
Junction and Storage	T_j	150	$^\circ\text{C}$
Temperature Range	T_s	- 65 to + 150	$^\circ\text{C}$

¹⁾ Alumina = 0.4 X 0.3 X 0.024 in, 99.5% alumina



SOT-23		
Dim	Min	Max
A	0.37	0.51
B	1.20	1.40
C	2.30	2.50
D	0.89	1.03
E	0.45	0.60
G	1.78	2.05
H	2.80	3.00
J	0.013	0.10
K	0.903	1.10
L	0.45	0.61
M	0.085	0.180
α	0°	8°
All Dimensions in mm		

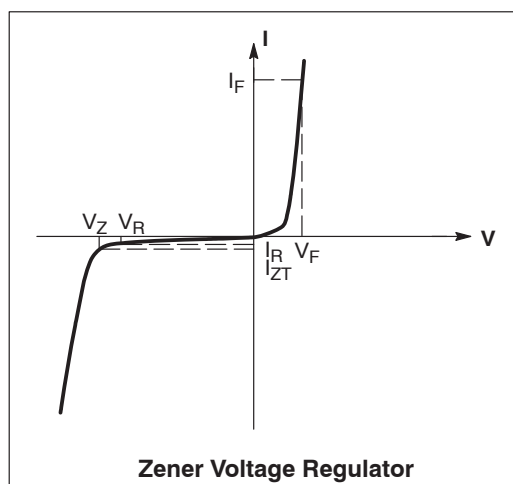
Device Schematic



ELECTRICAL CHARACTERISTICS

(Pinout: 1-Anode, 2-No Connection, 3-Cathode) ($T_A = 25^\circ\text{C}$ unless otherwise noted, $V_F = 0.90\text{ V Max.}$ @ $I_F = 10\text{ mA}$)

Symbol	Parameter
V_Z	Reverse Zener Voltage @ I_{ZT}
I_{ZT}	Reverse Current
Z_{ZT}	Maximum Zener Impedance @ I_{ZT}
I_R	Reverse Leakage Current @ V_R
V_R	Reverse Voltage
I_F	Forward Current
V_F	Forward Voltage @ I_F
θV_Z	Maximum Temperature Coefficient of V_Z
C	Max. Capacitance @ $V_R = 0$ and $f = 1\text{ MHz}$





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Type	Marking Code	Zener Voltage Range 1)				Dynamic Impedance				Reverse Leakage Current	
		VZT			at IZT	ZZT	at IZT	ZZK	at IZK	IR	at VR
		Nom. (V)	Min. (V)	Max. (V)	(mA)	Max. (Ω)	(mA)	Max. (Ω)	(mA)	Max. (μA)	(V)
BZX84C2V0	A8	2	1.8	2.15	5	100	5	-	-	120	0.5
BZX84C2V2	B8	2.2	2.08	2.33	5	100	5	-	-	120	0.7
BZX84C2V4	C8	2.4	2.2	2.6	5	100	5	600	1	50	1
BZX84C2V7	D8	2.7	2.5	2.9	5	100	5	600	1	20	1
BZX84C3V0	E8	3	2.8	3.2	5	95	5	600	1	10	1
BZX84C3V3	F8	3.3	3.1	3.5	5	95	5	600	1	5	1
BZX84C3V6	H8	3.6	3.4	3.8	5	90	5	600	1	5	1
BZX84C3V9	J8	3.9	3.7	4.1	5	90	5	600	1	3	1
BZX84C4V3	K8	4.3	4	4.6	5	90	5	600	1	3	1
BZX84C4V7	M8	4.7	4.4	5	5	80	5	500	1	3	2
BZX84C5V1	N8	5.1	4.8	5.4	5	60	5	480	1	2	2
BZX84C5V6	P8	5.6	5.2	6	5	40	5	400	1	1	2
BZX84C6V2	R8	6.2	5.8	6.6	5	10	5	150	1	3	4
BZX84C6V8	X8	6.8	6.4	7.2	5	15	5	80	1	2	4
BZX84C7V5	Y8	7.5	7	7.9	5	15	5	80	1	1	5
BZX84C8V2	Z8	8.2	7.7	8.7	5	15	5	80	1	0.7	5
BZX84C9V1	A9	9.1	8.5	9.6	5	15	5	100	1	0.5	6
BZX84C10	B9	10	9.4	10.6	5	20	5	150	1	0.2	7
BZX84C11	C9	11	10.4	11.6	5	20	5	150	1	0.1	8
BZX84C12	D9	12	11.4	12.7	5	25	5	150	1	0.1	8
BZX84C13	E9	13	12.4	14.1	5	30	5	170	1	0.1	8
BZX84C15	F9	15	13.8	15.6	5	30	5	200	1	0.05	10.5
BZX84C16	H9	16	15.3	17.1	5	40	5	200	1	0.05	11.2
BZX84C18	J9	18	16.8	19.1	5	45	5	225	1	0.05	12.6
BZX84C20	K9	20	18.8	21.2	5	55	5	225	1	0.05	14
BZX84C22	M9	22	20.8	23.3	5	55	5	250	1	0.05	15.4
BZX84C24	N9	24	22.8	25.6	5	70	5	250	1	0.05	16.8
BZX84C27	P9	27	25.1	28.9	2	80	2	300	0.5	0.05	18.9
BZX84C30	R9	30	28	32	2	80	2	300	0.5	0.05	21
BZX84C33	X9	33	31	35	2	80	2	325	0.5	0.05	23.1
BZX84C36	Y9	36	34	38	2	90	2	350	0.5	0.05	25.2
BZX84C39	Z9	39	37	41	2	130	2	350	0.5	0.05	27.3
BZX84C43	A0	43	40	46	2	150	2	375	0.5	0.05	30.1
BZX84C47	B0	47	44	50	2	170	2	375	0.5	0.05	32.9
BZX84C51	C0	51	48	54	2	180	2	400	0.5	0.05	35.7
BZX84C56	D0	56	52	60	2	200	2	425	0.5	0.05	39.2
BZX84C62	E0	62	58	66	2	215	2	450	0.5	0.05	43.4
BZX84C68	F0	68	64	72	2	240	2	475	0.5	0.05	47.6
BZX84C75	H0	75	70	79	2	255	2	500	0.5	0.05	52.5

¹⁾ Tested with pulses t_p = 20 ms.

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

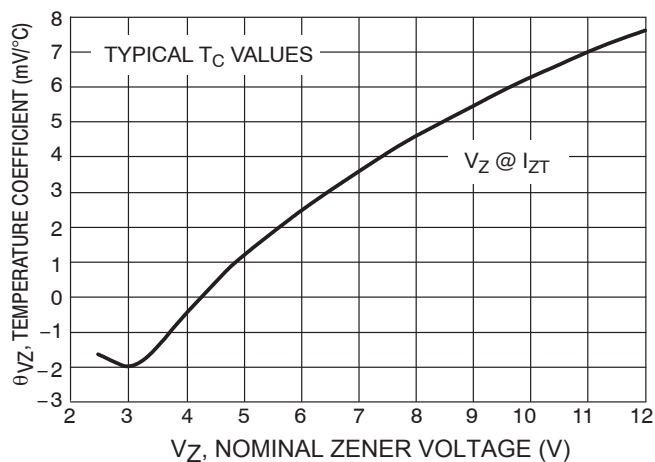


Figure 1. Temperature Coefficients
(Temperature Range -55°C to $+150^\circ\text{C}$)

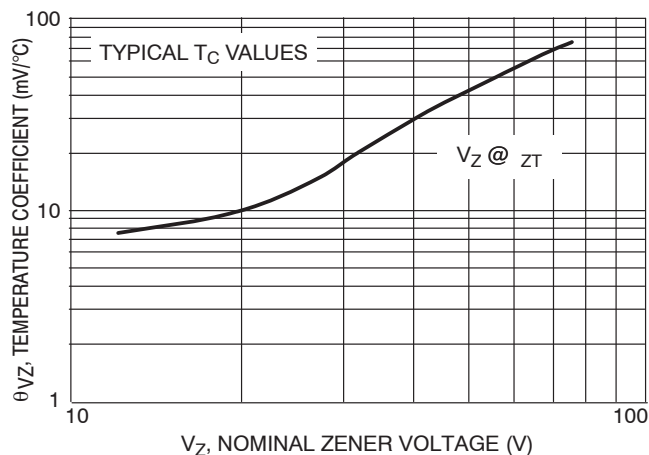


Figure 2. Temperature Coefficients
(Temperature Range -55°C to $+150^\circ\text{C}$)

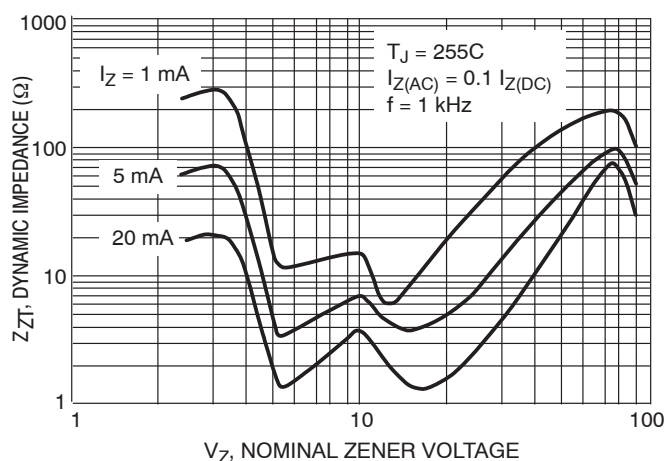


Figure 3. Effect of Zener Voltage on
Zener Impedance

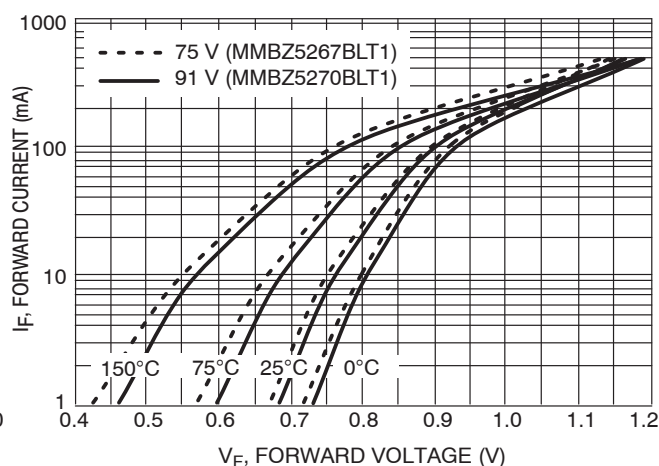


Figure 4. Typical Forward Voltage

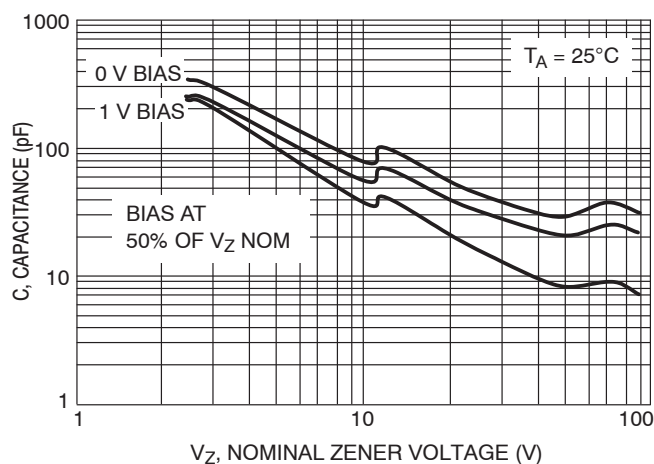


Figure 5. Typical Capacitance

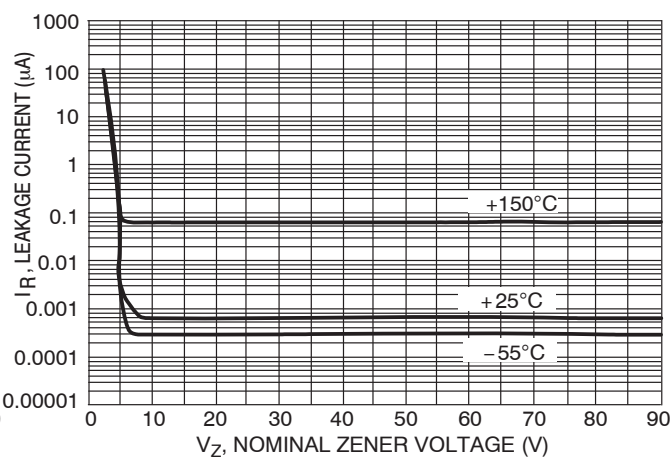


Figure 6. Typical Leakage Current



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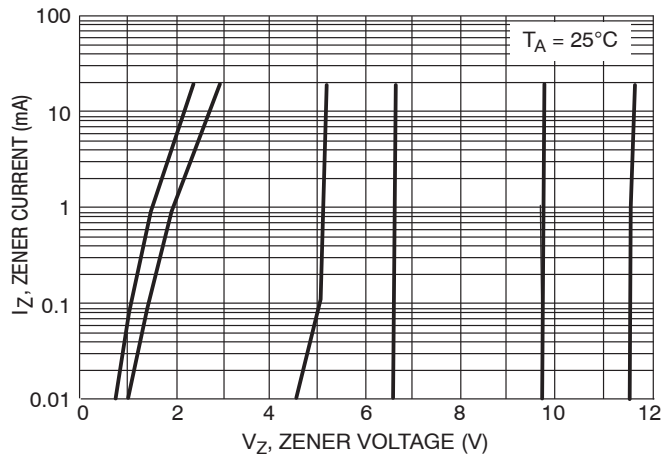


Figure 7. Zener Voltage versus Zener Current
(V_Z Up to 12 V)

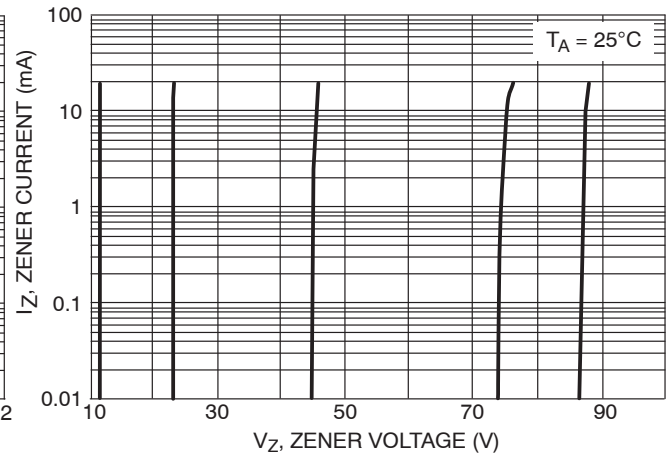


Figure 8. Zener Voltage versus Zener Current
(12 V to 91 V)

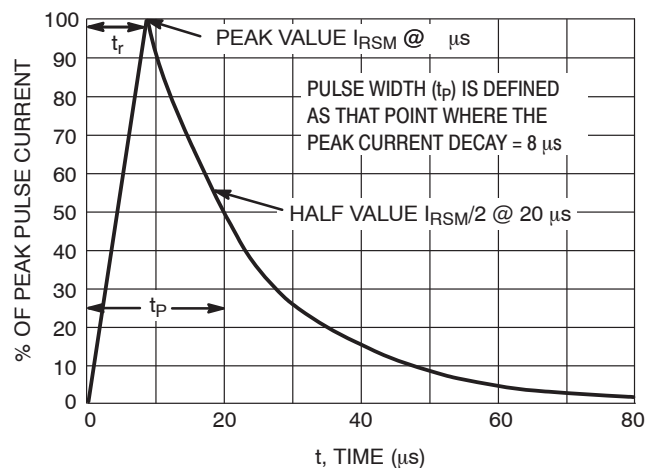


Figure 9. $8 \times 20 \mu\text{s}$ Pulse Waveform

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